

	L #	Hits	Search Text	DBs
1	L1	9844	ptc or positive adj (temp or temperature)	USPAT
2	L2	170094	dielectric	USPAT
3	L3	321517	semiconductive or semiconductor	USPAT
4	L4	1	1 with 2 with 3	USPAT
5	L5	3	1 with 3 same 2	USPAT
6	L6	10	1 same 3 same 2	USPAT
7	L7	25408	3 with 2	USPAT
8	L8	78	1 and 7	USPAT
9	L9	1	("4736230").PN.	USPAT
10	L10	11436	ptc or positive adj (temp or temperature)	EPO; JPO; DERWENT; IBM_TD_B
11	L11	215464	dielectric	EPO; JPO; DERWENT; IBM_TD_B
12	L12	993185	semiconductive or semiconductor	EPO; JPO; DERWENT; IBM_TD_B
13	L13	16	10 and 11 and 12	EPO; JPO; DERWENT; IBM_TD_B
14	L14	41	10 and dielectric adj constant	EPO; JPO; DERWENT; IBM_TD_B
15	L15	5747	ptc or positive adj (temp or temperature) with dielectric adj constant	USPAT

	L #	Hits	Search Text	DBs
16	L16	336	15 with barium adj titanate	USPAT
17	L17	31	(ptc or positive adj (temp or temperature)) with dielectric adj constant	USPAT
18	L18	1	("4386985").PN.	USPAT
19	L19	27	(ptc or positive adj (temp or temperature)) with dielectric adj constant	EPO; JPO; DERWENT; IBM_TD_B
20	L20	1	("6641898").PN.	USPAT
21	L21	15	3 with barium adj titanate with dielectric adj constant	USPAT
22	L22	19	(semiconductor or semiconductive) same barium adj titanate same dielectric adj constant	EPO; JPO; DERWENT; IBM_TD_B